SAR Test Report

Report No.: AGC00552200802FH01

FCC ID	:	2AHZ5NOTE20PRO
APPLICATION PURPOSE	:	Original Equipment
PRODUCT DESIGNATION	:	Smart Phone
BRAND NAME	:	CUBOT
MODEL NAME	:	NOTE 20 PRO
APPLICANT	:	Shenzhen Huafurui Technology Co., Ltd.
DATE OF ISSUE	:	Sep. 09,2020
STANDARD(S)	:	IEEE Std. 1528:2013 FCC 47 CFR Part 2§2.1093:2013 IEEE Std C95.1 ™-2005 IEC 62209-1: 2016
REPORT VERSION	:	V1.0

Attestation of Global Compliance(Shenzhen) Co., Ltd.

Report Revise Record

Report Version	Revise Time	Issued Date	Valid Version	Notes
V1.0	/	Sep. 09,2020	Valid	Initial Release

Test Report

Applicant Name	Shenzhen Huafurui Technology Co., Ltd.
Applicant Address	Unit 1401 14/F, Jin qi zhi gu mansion Liu xian street, Xili, Nan shan district, Shenzhen, China
Manufacturer Name	Shenzhen Huafurui Technology Co., Ltd.
Manufacturer Address	Unit 1401 14/F, Jin qi zhi gu mansion Liu xian street, Xili, Nan shan district, Shenzhen, China
Factory Name	Shenzhen Huafurui Technology Co., Ltd.
Factory Address	Unit 1401 14/F, Jin qi zhi gu mansion Liu xian street, Xili, Nan shan district, Shenzhen, China
Product Designation	Smart Phone
Brand Name	CUBOT
Model Name	NOTE 20 PRO
EUT Voltage	DC3.85V by battery
Applicable Standard	IEEE Std. 1528:2013 FCC 47 CFR Part 2§2.1093:2013 IEEE Std C95.1 ™-2005 IEC 62209-1: 2016
Test Date	Aug. 15,2020 to Aug. 31,2020
Report Template	AGCRT-US-4G/SAR (2018-01-01)

Note: The results of testing in this report apply to the product/system which was tested only.

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Reviewed By

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Approved By

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1. SUMMARY OF MAXIMUM SAR VALUE

The maximum results of Specific Absorption Rate (SAR) found during testing for EUT are as follows:

Frequency Band	Highest Reported 1g-SAR(W/Kg)		SAR Test Limit (W/Kg)
	Head	Body-worn	
GSM 850	0.157	0.167	1.6
PCS 1900	0.081	0.340	
UMTS Band II	0.106	0.460	
UMTS Band IV	0.098	0.397	
UMTS Band V	0.141	0.214	
LTE Band 2	0.140	0.588	
LTE Band 4	0.263	0.965	
LTE Band 5	0.142	0.094	
LTE Band 7	0.098	0.766	
LTE Band 12	0.022	0.029	
LTE Band 17	0.021	0.029	
Simultaneous Reported SAR	1.139		
SAR Test Result	PASS		

This device is compliance with Specific Absorption Rate (SAR) for general population/uncontrolled exposure limits (1.6W/Kg) specified in IEEE Std. 1528:2013; FCC 47CFR § 2.1093; IEEE/ANSI C95.1:2005 and the following specific FCC Test Procedures:

- KDB 447498 D01 General RF Exposure Guidance v06
- KDB 648474 D04 Handset SAR v01r03
- KDB 865664 D01 SAR Measurement 100MHz to 6GHz v01r04
- KDB 941225 D01 3G SAR Procedures v03r01
- KDB 941225 D06 Hotspot Mode v02r01
- KDB 941225 D05 SAR for LTE Devices v02r05

2. GENERAL INFORMATION

2.1. EUT Description

General Information	
Product Designation	Smart Phone
Test Model	NOTE 20 PRO
Hardware Version	LV966_MB_V1.0
Software Version	CUBOT_NOTE 20 PRO_A013C_V02_20200729
Device Category	Portable
RF Exposure Environment	Uncontrolled
Antenna Type	Internal
GSM and GPRS& EGPRS	
Support Band	☒GSM 850 ☒PCS 1900 ☐GSM 900 ☐DCS 1800
GPRS & EGPRS Type	Class B
GPRS & EGPRS Class	Class 12(1Tx+4Rx, 2Tx+3Rx, 3Tx+2Rx, 4Tx+1Rx)
TX Frequency Range	GSM 850 : 820-850MHz; PCS 1900: 1850-1910MHz;
RX Frequency Range	GSM 850 : 869~894MHz; PCS 1900: 1930~1990MHz
Release Version	R99
Type of modulation	GMSK for GSM/GPRS; GMSK & 8-PSK for EGPRS
Antenna Gain	GSM850:1.52dBi; PCS1900: 1.44dBi
Max. Average Power	GSM850: 32.84dBm; PCS1900: 30.57dBm
WCDMA	
Support Band	☒UMTS FDD Band II ☒UMTS FDD Band V ☒UMTS FDD Band IV ☐UMTS FDD Band I ☐UMTS FDD Band III ☐UMTS FDD Band VIII
HS Type	HSPA(HSUPA/HSDPA)
TX Frequency Range	FDD Band II: 1850-1910MHz; FDD Band V: 820-850MHz FDD Band IV: 1712.4-1752.6MHz
RX Frequency Range	FDD Band II: 1930-1990MHz; FDD Band V: 869-894MHz FDD Band IV: 2112.4-5152.6MHz
Release Version	Rel-6
Type of modulation	HSDPA:QPSK/16QAM; HSUPA:BPSK; WCDMA:QPSK
Antenna Gain	WCDMA850:1.52dBi; Band1700: 1.78dBi; WCDMA1900:1.44dBi
Max. Average Power	Band II: 24.04dBm; Band IV: 23.20dBm; Band V: 23.75dBm

EUT Description(Continue)

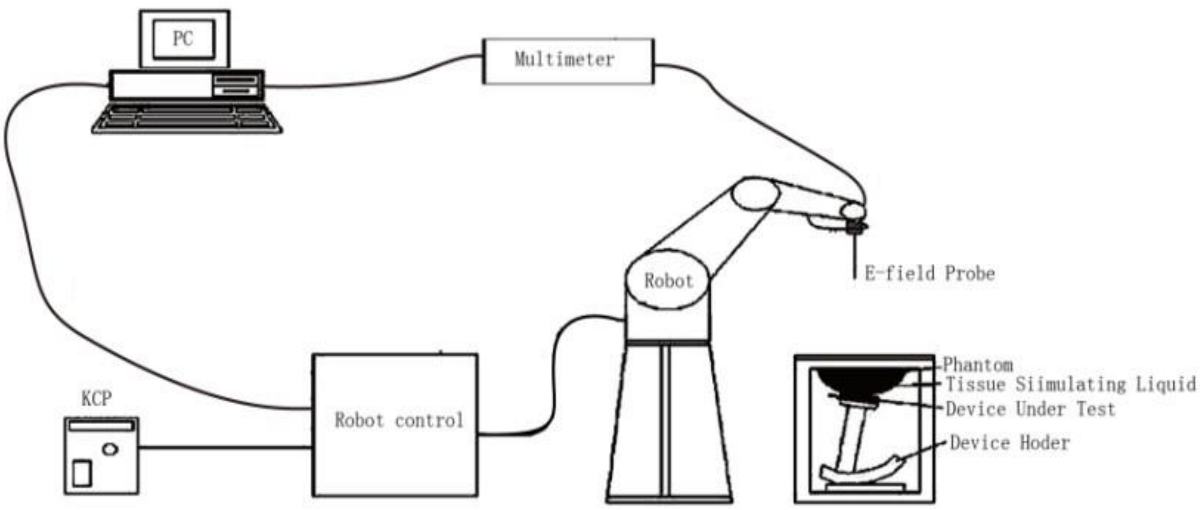
LTE	
Support Band	☒FDD Band 2 ☒FDD Band 4 ☒FDD Band 5 ☒FDD Band 7 ☒FDD Band 12 ☒FDD Band 17 ☐FDD Band 25 ☐FDD Band 26 ☐TDD Band 41 (U.S. Bands) ☐FDD Band 1 ☐FDD Band 3 ☐FDD Band 7 ☐FDD Band 8 ☐FDD Band 20 ☐TDD Band 28 ☐TDD Band 38 ☐FDD Band 40 ☐FDD Band 42 ☐FDD Band 43 (Non-U.S. Bands)
TX Frequency Range	Band 2:1850-1910MHz; Band 4:1710-1755MHz;Band 5:824-849MHz; Band 7:2500-2570MHz; Band 12:699-716MHz; Band 17: 704-716MHz;
RX Frequency Range	Band 2:1930-1990MHz; Band 4:2110-2155MHz; Band 5:869-894MHz; Band 7:2620-2690MHz; Band 12: 729-746 MHz; Band 17: 734-746 MHz;
Release Version	Rel-8
Type of modulation	QPSK, 16QAM
Antenna Gain	Band 2: 1.44dBi; Band 4: 1.78dBi; Band 5:1.22dBi; Band 7: 1.57dBi; Band 12:1.25dBi; Band 17:1.37dBi
Max. Average Power	Band 2: 24.89dBm; Band 4: 24.03dBm; Band 5: 23.70dBm; Band 7: 24.02dBm; Band 12: 24.07dBm; Band 17: 24.08dBm;
Bluetooth	
Bluetooth Version	☐V2.0 ☐V2.1 ☐V2.1+EDR ☐V3.0 ☐V3.0+HS ☐V4.0 ☒V4.2
Operation Frequency	2402~2480MHz
Type of modulation	☒GFSK ☒Π/4-DQPSK ☒8-DPSK
Peak Power	-0.486dBm
Antenna Gain	0dBi
WIFI	
WIFI Specification	☐802.11a ☒802.11b ☒802.11g ☒802.11n(20) ☒802.11n(40)
Operation Frequency	2412~2462MHz
Avg. Burst Power	11b: 9.16dBm,11g: 7.11dBm,11n(20): 6.80dBm,11n(40): 7.19dBm
Antenna Gain	0dBi
Accessories	
Battery	Brand name: CUBOT Model No. : NOTE 20 Voltage and Capacitance: 3.85 V & 4200mAh
Earphone	Brand name: N/A Model No. : N/A

Note:1.CMU200 can measure the average power and Peak power at the same time
2.The sample used for testing is end product.
3. The test sample has no any deviation to the test method of standard mentioned in page 1.

Product	Type	
	☒ Production unit	☐ Identical Prototype

3. SAR MEASUREMENT SYSTEM

3.1. The SATIMO system used for performing compliance tests consists of following items



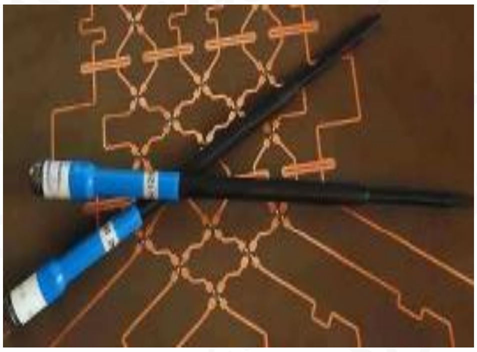
The COMOSAR system for performing compliance tests consists of the following items:

- The PC. It controls most of the bench devices and stores measurement data.A computer running WinXP and the Opensar software.
- The E-Field probe. The probe is a 3-axis system made of 3 distinct dipoles. Each dipole returns a voltage in function of the ambient electric field.
- The Keithley multimeter measures each probe dipole voltages.
- The SAM phantom simulates a human head. The measurement of the electric field is made inside the phantom.
- The liquids simulate the dielectric properties of the human head tissues.
- The network emulator controls the mobile phone under test.
- The validation dipoles are used to measure a reference SAR. They are used to periodically check the bench to make sure that there is no drift of the system characteristics over time.
- The phantom, the device holder and other accessories according to the targeted measurement.

3.2. COMOSAR E-Field Probe

The SAR measurement is conducted with the dosimetric probe manufactured by SATIMO. The probe is specially designed and calibrated for use in liquid with high permittivity. The dosimetric probe has special calibration in liquid at different frequency. SATIMO conducts the probe calibration in compliance with international and national standards (e.g. IEEE 1528 and relevant KDB files.) The calibration data are in Appendix D.

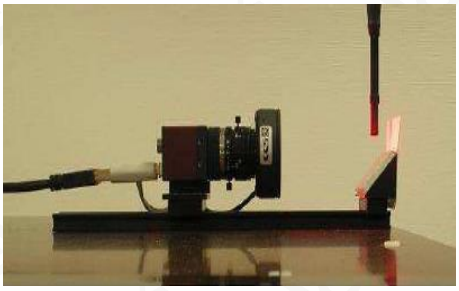
Isotropic E-Field Probe Specification

Model	SSE5	
Manufacture	MVG	
Identification No.	SN 24/20 EP336	
Frequency	0.7GHz-3GHz Linearity:±0.08dB(0.7GHz-3GHz)	
Dynamic Range	0.01W/Kg-100W/Kg Linearity:±0.08dB	
Dimensions	Overall length:330mm Length of individual dipoles:4.5mm Maximum external diameter:8mm Probe Tip external diameter:5mm Distance between dipoles/ probe extremity:2.7mm	
Application	High precision dosimetric measurements in any exposure scenario (e.g., very strong gradient fields). Only probe which enables compliance testing for frequencies up to 3 GHz with precisin of better 30%.	

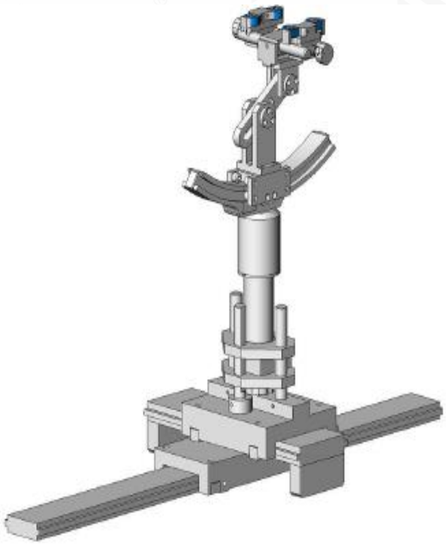
3.3. Robot

The COMOSAR system uses the KUKA robot from SATIMO SA (France).For the 6-axis controller COMOSAR system, the KUKA robot controller version from SATIMO is used. The XL robot series have many features that are important for our application: High precision (repeatability 0.02 mm) High reliability (industrial design) Jerk-free straight movements Low ELF interference (the closed metallic construction shields against motor control fields) 6-axis controller	

3.4. Video Positioning System

The video positioning system is used in OpenSAR to check the probe. Which is composed of a camera, LED, mirror and mechanical parts.The camera is piloted by the main computer with firewire link. During the process, the actual position of the probe tip with respect to the robot arm is measured, as well as the probe length and the horizontal probe offset. The software then corrects all movements, such that the robot coordinates are valid for the probe tip. The repeatability of this process is better than 0.1 mm. If a position has been taught with an aligned probe, the same position will be reached with another aligned probe within 0.1 mm, even if the other probe has different dimensions. During probe rotations, the probe tip will keep its actual position.	

3.5. Device Holder

The COMOSAR device holder is designed to cope with different positions given in the standard. It has two scales for the device rotation (with respect to the body axis) and the device inclination (with respect to the line between the ear reference points). The rotation center for both scales is the ear reference point (EPR). Thus the device needs no repositioning when changing the angles. The COMOSAR device holder has been made out of low-loss POM material having the following dielectric parameters: relative permittivity εr =3 and loss tangent δ = 0.02. The amount of dielectric material has been reduced in the closest vicinity of the device, since measurements have suggested that the influence of the clamp on the test results could thus be lowered.	

3.6. SAM Twin Phantom

The SAM twin phantom is a fiberglass shell phantom with 2mm shell thickness (except the ear region where shell thickness increases to 6mm). It has three measurement areas: □ Left head □ Right head □ Flat phantom	

The bottom plate contains three pair of bolts for locking the device holder. The device holder positions are adjusted to the standard measurement positions in the three sections. A white cover is provided to tap the phantom during off-periods to prevent water evaporation and changes in the liquid parameters. On the phantom top, three reference markers are provided to identify the phantom position with respect to the robot.

ELLI39 Phantom

The Flat phantom is a fiberglass shellphantom with 2mm+/- 0.2 mm shell thickness. It has only one measurement area for Flat phantom	

4. SAR MEASUREMENT PROCEDURE

4.1. Specific Absorption Rate (SAR)

SAR is related to the rate at which energy is absorbed per unit mass in object exposed to a radio field. The SAR distribution in a biological body is complicated and is usually carried out by experimental techniques or numerical modeling. The standard recommends limits for two tiers of groups, occupational/controlled and occupational/uncontrolled, based on a person's awareness and ability to exercise control over his or her exposure. In general, occupational/controlled exposure limits are higher than the limits for general population/uncontrolled.

The SAR definition is the time derivative (rate) of the incremental energy (dW) absorbed by (dissipated in) an incremental mass (dm) contained in a volume element(dv) of given mass density (ρ). The equation description is as below:

$$SAR = \frac{d}{dt}\left(\frac{dW}{dm}\right) = \frac{d}{dt}\left(\frac{dW}{\rho dV}\right)$$

SAR is expressed in units of Watts per kilogram (W/Kg)
SAR can be obtained using either of the following equations:

$$SAR = \frac{\sigma E^2}{\rho}$$

$$SAR = c_h \frac{dT}{dt}\bigg|_{t=0}$$

Where

SAR	is the specific absorption rate in watts per kilogram;
E	is the r.m.s. value of the electric field strength in the tissue in volts per meter;
σ	is the conductivity of the tissue in siemens per metre;
ρ	is the density of the tissue in kilograms per cubic metre;
c_h	is the heat capacity of the tissue in joules per kilogram and Kelvin;
$\frac{dT}{dt} \mid t = 0$	is the initial time derivative of temperature in the tissue in kelvins per second

4.2. SAR Measurement Procedure

Step 1: Power Reference Measurement

The Power Reference Measurement and Power Drift Measurement are for monitoring the power drift of the device under test in the batch process. The minimum distance of probe sensors to surface is 2.7mm This distance cannot be smaller than the distance os sensor calibration points to probe tip as `defined in the probe properties,

Step 2: Area Scan

The Area Scan is used as a fast scan in two dimensions to find the area of high field values, before doing a fine measurement around the hot spot. The sophisticated interpolation routines implemented in SATIMO software can find the maximum locations even in relatively coarse grids. When an Area Scan has measured all reachable points, it computes the field maximal found in the scanned area, within a range of the global maximum. The range (in db) is specified in the standards for compliance testing. For example, a 2db range is required in IEEE Standard 1528 and IEC62209 standards, whereby 3db is a requirement when compliance is assessed in accordance with the ARIB standard (Japan) If one Zoom Scan follows the Area Scan, then only the absolute maximum will be taken as reference. For cases where multiple maximum are detected, the number of Zoom Scan has to be increased accordingly.

Area Scan Parameters extracted from KDB 865664 D01 SAR Measurement 100MHz to 6GHz

	≤ 3 GHz	> 3 GHz
Maximum distance from closest measurement point (geometric center of probe sensors) to phantom surface	5 ± 1 mm	½·δ·ln(2) ± 0.5 mm
Maximum probe angle from probe axis to phantom surface normal at the measurement location	30° ± 1°	20° ± 1°
Maximum area scan spatial resolution: Δx_{Area}, Δy_{Area}	≤ 2 GHz: ≤ 15 mm 2 – 3 GHz: ≤ 12 mm	3 – 4 GHz: ≤ 12 mm 4 – 6 GHz: ≤ 10 mm
	When the x or y dimension of the test device, in the measurement plane orientation, is smaller than the above, the measurement resolution must be ≤ the corresponding x or y dimension of the test device with at least one measurement point on the test device.	

Step 3: Zoom Scan

Zoom Scan are used to assess the peak spatial SAR value within a cubic average volume containing 1g abd 10g of simulated tissue. The Zoom Scan measures points(refer to table below) within a cube whose base faces are centered on the maxima found in a preceding area scan job within the same procedure. When the measurement is done, the Zoom Scan evaluates the averaged SAR for 1g and 10g and displays these values next to the job’s label.

Zoom Scan Parameters extracted from KDB865664 d01 SAR Measurement 100MHz to 6GHz

Maximum zoom scan spatial resolution: Δx_{Zoom}, Δy_{Zoom}			≤ 2 GHz: ≤ 8 mm 2 – 3 GHz: ≤ 5 mm*	3 – 4 GHz: ≤ 5 mm* 4 – 6 GHz: ≤ 4 mm*
Maximum zoom scan spatial resolution, normal to phantom surface	uniform grid: $\Delta z_{Zoom}(n)$		≤ 5 mm	3 – 4 GHz: ≤ 4 mm 4 – 5 GHz: ≤ 3 mm 5 – 6 GHz: ≤ 2 mm
	graded grid	$\Delta z_{Zoom}(1)$: between 1st two points closest to phantom surface	≤ 4 mm	3 – 4 GHz: ≤ 3 mm 4 – 5 GHz: ≤ 2.5 mm 5 – 6 GHz: ≤ 2 mm
		$\Delta z_{Zoom}(n>1)$: between subsequent points	$\leq 1.5 \cdot \Delta z_{Zoom}(n-1)$	
Minimum zoom scan volume	x, y, z		≥ 30 mm	3 – 4 GHz: ≥ 28 mm 4 – 5 GHz: ≥ 25 mm 5 – 6 GHz: ≥ 22 mm
Note: δ is the penetration depth of a plane-wave at normal incidence to the tissue medium; see draft standard IEEE P1528-2011 for details. * When zoom scan is required and the *reported* SAR from the *area scan based 1-g SAR estimation* procedures of KDB 447498 is ≤ 1.4 W/kg, ≤ 8 mm, ≤ 7 mm and ≤ 5 mm zoom scan resolution may be applied, respectively, for 2 GHz to 3 GHz, 3 GHz to 4 GHz and 4 GHz to 6 GHz.				

Step 4: Power Drift Measurement

The Power Drift Measurement measures the field at the same location as the most recent power reference measurement within the same procedure, and with the same settings. The Power Drift Measurement gives the field difference in dB from the reading conducted within the same settings. This allows a user to monitor the power drift of the device under test within a batch process. The measurement procedure is the same as Step 1.

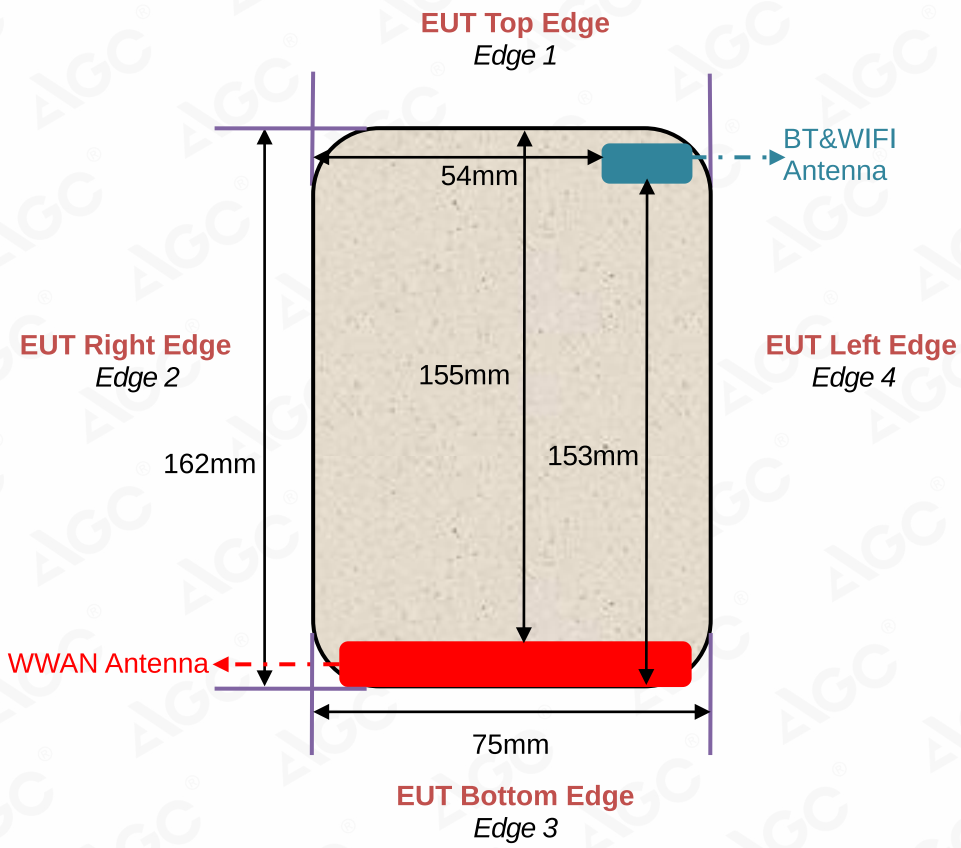
4.3. RF Exposure Conditions

Test Configuration and setting:

The EUT is a model of GSM Portable Mobile Station (MS). It supports GSM/GPRS/EGPRS, WCDMA/HSPA, LTE, BT, WIFI, and support hot spot mode.

For WWAN SAR testing, the device was controlled by using a base station emulator. Communication between the device and the emulator were established by air link. The distance between the EUT and the antenna is larger than 50cm, and the output power radiated from the emulator antenna is at least 30db smaller than the output power of EUT.

Antenna Location: (the back view)



For WWAN mode:

Test Configurations	Antenna to edges/surface	SAR required	Note
Head			
Left Touch		Yes	--
Left Tilt		Yes	--
Right Touch		Yes	--
Right Tilt		Yes	--
Body			
Back	<25mm	Yes	--
Front	<25mm	Yes	--
Hotspot			
Back	<25mm	Yes	--
Front	<25mm	Yes	--
Edge 1 (Top)	155mm	No	SAR is not required for the distance between the antenna and the edge is >25mm as per KDB 941225 D06 Hotspot SAR
Edge 2 (Right)	1mm	Yes	--
Edge 3 (Bottom)	1mm	Yes	--
Edge 4 (Left)	1mm	Yes	--

5. TISSUE SIMULATING LIQUID

For SAR measurement of the field distribution inside the phantom, the phantom must be filled with homogeneous tissue simulating liquid to a depth of at least 15cm. For head SAR testing the liquid height from the ear reference point (ERP) of the phantom to the liquid top surface is larger than 15cm For body SAR testing, the liquid height from the center of the flat phantom to the liquid top surface is larger than 15cm.The nominal dielectric values of the tissue simulating liquids in the phantom and the tolerance of 10% are listed in 6.2

5.1. The composition of the tissue simulating liquid

Ingredient (% Weight) / Frequency (MHz)	Water	Nacl	Polysorbate 20	DGBE	1,2 Propanediol	Triton X-100
750 Head	35	2	0.0	0.0	63	0.0
835 Head	50.36	1.25	48.39	0.0	0.0	0.0
1750 Head	52.64	0.36	0.0	47	0.0	0.0
1900 Head	54.9	0.18	0.0	44.92	0.0	0.0
2600 Head	55.242	0.306	0	44.452	0	0

5.2. Tissue Dielectric Parameters for Head and Body Phantoms

The head tissue dielectric parameters recommended by the IEC 62209-1 have been incorporated in the following table. The body tissue dielectric parameters recommended by the IEC 62209-2 have been incorporated in the following table.

Target Frequency (MHz)	head		body	
	εr	σ (S/m)	εr	σ (S/m)
300	45.3	0.87	45.3	0.87
450	43.5	0.87	43.5	0.87
750	**41.9**	**0.89**	**41.9**	**0.89**
835	**41.5**	**0.90**	**41.5**	**0.90**
900	41.5	0.97	41.5	0.97
915	41.5	1.01	41.5	1.01
1450	40.5	1.20	40.5	1.20
1610	40.3	1.29	40.3	1.29
1750	**40.1**	**1.37**	**40.1**	**1.37**
1800 – 2000	**40.0**	**1.40**	**40.0**	**1.40**
2450	39.2	1.80	39.2	1.80
2600	**39.0**	**1.96**	**39.0**	**1.96**
3000	38.5	2.40	38.5	2.40

(εr = relative permittivity, σ = conductivity and ρ = 1000 kg/m3

5.3. Tissue Calibration Result

The dielectric parameters of the liquids were verified prior to the SAR evaluation using SATIMO Dielectric Probe Kit and R&S Network Analyzer ZVL6.

Tissue Stimulant Measurement for 750MHz					
Head	Fr. (MHz)	Dielectric Parameters (±10%)		Tissue Temp [°C]	Test time
		εr 41.9 (37.71-46.09)	δ[s/m] 0.89(0.801-0.979)		
	707.5	43.73	0.88	20.7	Aug. 22,2020
	710	43.61	0.90		
	750	42.57	0.91		

Tissue Stimulant Measurement for 835MHz					
Head	Fr. (MHz)	Dielectric Parameters (±10%)		Tissue Temp [°C]	Test time
		εr 41.5 (37.35-45.65)	δ[s/m] 0.90(0.81-0.99)		
	835	40.21	0.88	21.3	Aug. 21,2020
	836.6	39.62	0.91		

Tissue Stimulant Measurement for 835MHz					
Head	Fr. (MHz)	Dielectric Parameters (±10%)		Tissue Temp [°C]	Test time
		εr 41.5 (37.35-45.65)	δ[s/m] 0.90(0.81-0.99)		
	835	41.95	0.87	20.1	Aug. 15,2020
	836.5	40.53	0.89		

Tissue Stimulant Measurement for 1750MHz					
Head	Fr. (MHz)	Dielectric Parameters (±10%)		Tissue Temp [°C]	Test time
		εr 40.1 (36.09-44.11)	δ[s/m]1.37(1.233-1.507)		
	1720	41.26	1.31	20.5	Aug. 28,2020
	1732.5	40.83	1.32		
	1745	40.20	1.34		
	1750	39.67	1.36		

Tissue Stimulant Measurement for 1900MHz					
Head	Fr. (MHz)	Dielectric Parameters (±10%)		Tissue Temp [°C]	Test time
		εr40.00(36.00-44.00)	δ[s/m]1.40(1.26-1.54)		
	1880	39.55	1.41	21.1	Aug. 31,2020
	1900	39.18	1.43		

Tissue Stimulant Measurement for 1900MHz					
Head	Fr. (MHz)	Dielectric Parameters (±10%)		Tissue Temp [°C]	Test time
		εr40.00(36.00-44.00)	δ[s/m]1.40(1.26-1.54)		
	1880	40.02	1.34	21.4	Aug. 20,2020
	1900	39.54	1.36		

Tissue Stimulant Measurement for 2600MHz					
Head	Fr. (MHz)	Dielectric Parameters (±10%)		Tissue Temp [°C]	Test time
		εr39(35.1-42.9)	δ[s/m]1.96(1.764-2.156)		
	2535	39.91	1.85	19.2	Aug. 27,2020
	2600	38.62	1.88		

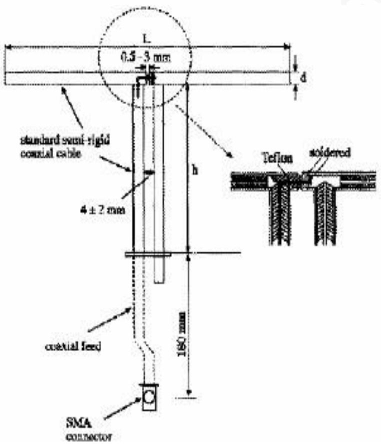
6. SAR SYSTEM CHECK PROCEDURE

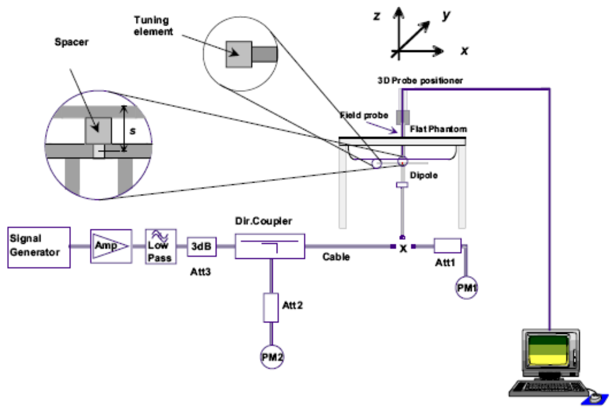
6.1. SAR System Check Procedures

SAR system check is required to confirm measurement accuracy, according to the tissue dielectric media, probe calibration points and other system operating parameters required for measuring the SAR of a test device. The system verification must be performed for each frequency band and within the valid range of each probe calibration point required for testing the device. The same SAR probe(s) and tissue-equivalent media combinations used with each specific SAR system for system verification must be used for device testing. When multiple probe calibration points are required to cover substantially large transmission bands, independent system verifications are required for each probe calibration point. A system verification must be performed before each series of SAR measurements using the same probe calibration point and tissue-equivalent medium. Additional system verification should be considered according to the conditions of the tissue-equivalent medium and measured tissue dielectric parameters, typically every three to four days when the liquid parameters are remeasured or sooner when marginal liquid parameters are used at the beginning of a series of measurements.

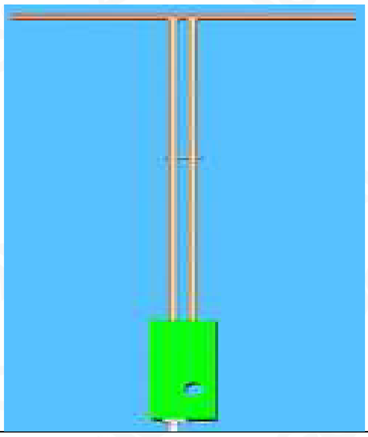
Each SATIMO system is equipped with one or more system check kits. These units, together with the predefined measurement procedures within the SATIMO software, enable the user to conduct the system check and system validation. System kit includes a dipole, and dipole device holder.

The system check verifies that the system operates within its specifications. It’s performed daily or before every SAR measurement. The system check uses normal SAR measurement in the flat section of the phantom with a matched dipole at a specified distance. The system check setup is shown as below.





6.2. SAR System Check
6.2.1. Dipoles



The dipoles used is based on the IEEE-1528 standard, and is complied with mechanical and electrical specifications in line with the requirements of IEEE. the table below provides details for the mechanical and electrical
Specifications for the dipoles.

Frequency	L (mm)	h (mm)	d (mm)
750MHz	176	100	6.35
835MHz	161.0	89.8	3.6
1800MHz	71.6	41.7	3.6
1900MHz	68	39.5	3.6
2600MHz	48.5	28.8	3.6

6.2.2. System Check Result

System Performance Check at 750MHz&835MHz &1800MHz &1900MHz &2600MHz for Head								
Validation Kit: SN47/14 DIP 0G750-340& SN29/15 DIP 0G835-383& SN46/11 DIP 1G800-186& SN 46/11 DIP 1G900-187& SN 47/14 DIP 2G600-342								
Frequency [MHz]	Target Value(W/Kg)		Reference Result (± 10%)		Tested Value(W/Kg)		Tissue Temp. [°C]	Test time
	1g	10g	1g	10g	1g	10g		
750	8.31	5.45	7.479-9.141	4.905-5.995	8.15	5.36	20.7	Aug. 22,2020
835	9.85	6.27	8.865-10.835	5.643-6.897	9.25	5.84	21.3	Aug. 21,2020
835	9.85	6.27	8.865-10.835	5.643-6.897	9.41	5.75	20.1	Aug. 15,2020
1800	39.07	20.29	35.163-42.977	18.261-22.319	38.19	19.30	20.5	Aug. 28,2020
1900	40.25	20.50	36.225-44.275	18.45-22.55	40.30	20.46	21.1	Aug. 31,2020
1900	40.25	20.50	36.225-44.275	18.45-22.55	39.32	19.86	21.4	Aug. 20,2020
2600	56.86	24.84	51.174-62.546	22.356-27.324	54.16	24.31	19.2	Aug. 27,2020
750	8.31	5.45	7.479-9.141	4.905-5.995	8.29	5.45	20.7	Aug. 22,2020
835	9.85	6.27	8.865-10.835	5.643-6.897	9.40	5.92	21.3	Aug. 21,2020
835	9.85	6.27	8.865-10.835	5.643-6.897	9.39	5.91	20.1	Aug. 15,2020
1800	39.07	20.29	35.163-42.977	18.261-22.319	36.93	18.82	20.5	Aug. 28,2020
1900	40.25	20.50	36.225-44.275	18.45-22.55	40.48	20.14	21.1	Aug. 31,2020
1900	40.25	20.50	36.225-44.275	18.45-22.55	40.29	19.93	21.4	Aug. 20,2020
2600	56.86	24.84	51.174-62.546	22.356-27.324	53.47	24.11	19.2	Aug. 27,2020

Note:
(1) We use a CW signal of 18dBm for system check, and then all SAR value are normalized to 1W forward power. The result must be within ±10% of target value.

7. EUT TEST POSITION

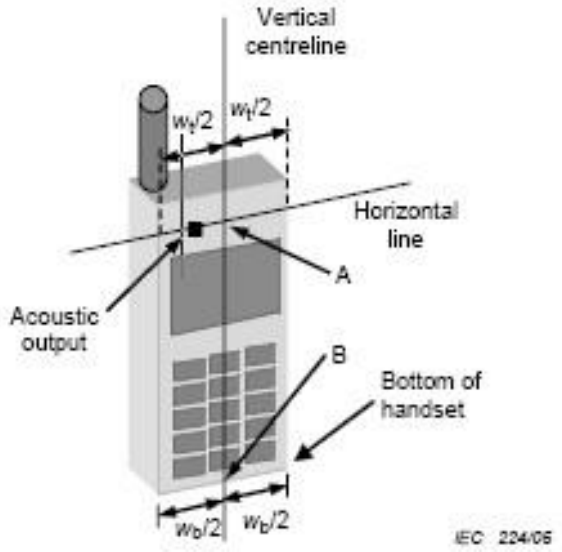
This EUT was tested in **Right Cheek, Right Tilted, Left Cheek, Left Tilted, Body back, Body front and 4 edges.**

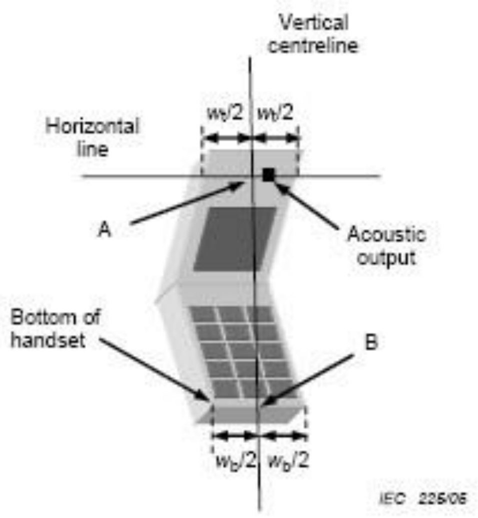
7.1. Define Two Imaginary Lines on the Handset

(1)The vertical centerline passes through two points on the front side of the handset the midpoint of the width wt of the handset at the level of the acoustic output, and the midpoint of the width wb of the handset.

(2)The horizontal line is perpendicular to the vertical centerline and passes through the center of the acoustic output. The horizontal line is also tangential to the face of the handset at point A.

(3)The two lines intersect at point A. Note that for many handsets, point A coincides with the center of the acoustic output; however, the acoustic output may be located elsewhere on the horizontal line. Also note that the vertical centerline is not necessarily to the front face of the handset, especially for clamshell handsets, handsets with flip covers, and other irregularly shaped handsets.





7.2. Cheek Position

(1) To position the device with the vertical center line of the body of the device and the horizontal line crossing the center picec in a plane parallel to the sagittal plane of the phantom. While maintaining the device in this plane, align the vertical center line with the reference plane containing the ear and mouth reference point (M: Mouth, RE: Right Ear, and LE: Left Ear) and align the center of the ear piece with the line RE-LE.

(2) To move the device towards the phantom with the ear piece aligned with the the line LE-RE until the phone touched the ear. While maintaining the device in the reference plane and maintaining the phone contact with ear, move the bottom of the phone until any point on the front side is in contact with the cheek of the phantom or until contact with the ear is lost

7.3. Tilt Position

(1) To position the device in the "cheek" position described above.

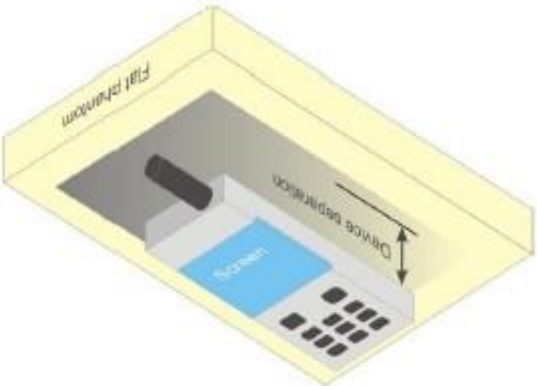
(2) While maintaining the device in the reference plane described above and pivoting against the ear, moves it outward away from the mouth by an angle of 15 degrees or until with the ear is lost.

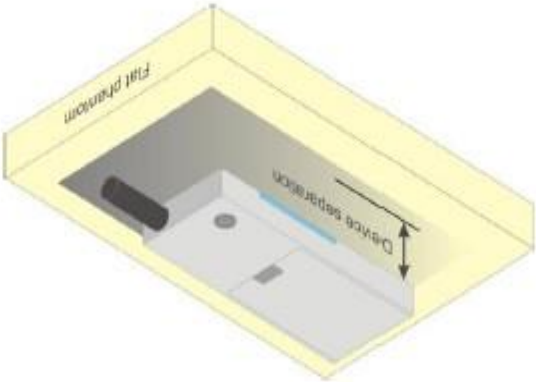
7.4. Body Worn Position

(1) To position the EUT parallel to the phantom surface.

(2) To adjust the EUT parallel to the flat phantom.

(3) To adjust the distance between the EUT surface and the flat phantom to **10mm.**





8. SAR EXPOSURE LIMITS

Limits for General Population/Uncontrolled Exposure (W/kg)

Type Exposure	Uncontrolled Environment Limit (W/kg)
Spatial Peak SAR (1g cube tissue for brain or body)	1.60
Spatial Average SAR (Whole body)	0.08
Spatial Peak SAR (Limbs)	4.0

9. TEST FACILITY

Test Site	Attestation of Global Compliance (Shenzhen) Co., Ltd
Location	1-2/F, Building 19, Junfeng Industrial Park, Chongqing Road, Heping Community, Fuhai Street, Bao'an District, Shenzhen, Guangdong, China
Designation Number	CN1259
FCC Test Firm Registration Number	975832
A2LA Cert. No.	5054.02
Description	Attestation of Global Compliance(Shenzhen) Co., Ltd is accredited by A2LA

10. TEST EQUIPMENT LIST

Equipment description	Manufacturer/ Model	Identification No.	Current calibration date	Next calibration date
SAR Probe	MVG	SN 24/20 EP336	Jun. 24,2020	Jun. 23,2021
Phantom	SATIMO	SN_4511_SAM90	Validated. No cal required.	Validated. No cal required.
Phantom	SATIMO	SN_2316_ELLI39	Validated. No cal required.	Validated. No cal required.
Liquid	SATIMO	-	Validated. No cal required.	Validated. No cal required.
Comm Tester	Agilent-8960	GB46310822	Oct. 08,2019	Oct. 07,2020
Comm Tester	R&S- CMW500	S/N120909	Aug. 12,2020	Aug. 11,2021
Multimeter	Keithley 2000	4114939	Sep. 09,2019	Sep. 08,2020
Dipole	SATIMO SID750	SN47/14 DIP 0G750-340	Apr. 26,2019	Apr. 25,2022
Dipole	SATIMO SID835	SN29/15 DIP 0G835-383	Apr. 26,2019	Apr. 25,2022
Dipole	SATIMO SID1800	SN46/11 DIP 1G800-186	Apr. 26,2019	Apr. 25,2022
Dipole	SATIMO SID1900	SN 46/11 DIP 1G900-187	Apr. 26,2019	Apr. 25,2022
Dipole	SATIMO SID2600	SN 47/14 DIP 2G600-342	Apr. 26,2019	Apr. 25,2022
Signal Generator	Agilent-E4438C	US41461365	Oct. 08,2019	Oct. 07,2020
Vector Analyzer	Agilent / E4440A	US41421290	Sep. 09,2019	Sep. 08,2020
Network Analyzer	Rhode & Schwarz ZVL6	SN101443	Oct. 08,2019	Oct. 07,2020
Attenuator	Warison /WATT-6SR1211	S/N:WRJ34AYM2F1	June 10,2020	June 09,2021
Attenuator	Mini-circuits / VAT-10+	31405	June 10,2020	June 09,2021
Amplifier	AS0104-55_55	1004793	June 11,2020	June 10,2021
Directional Couple	Werlatone/ C5571-10	SN99463	May 15,2020	May 14,2022
Directional Couple	Werlatone/ C6026-10	SN99482	May 15,2020	May 14,2022
Power Sensor	NRP-Z21	1137.6000.02	Sep. 09,2019	Sep. 08,2020
Power Sensor	NRP-Z23	US38261498	Feb. 18,2020	Feb. 17,2021
Power Viewer	R&S	V2.3.1.0	N/A	N/A

Note: Per KDB 865664 Dipole SAR Validation, AGC Lab has adopted 3 years calibration intervals. On annual basis, every measurement dipole has been evaluated and is in compliance with the following criteria:
1. There is no physical damage on the dipole;
2. System validation with specific dipole is within 10% of calibrated value;
3. Return-loss is within 20% of calibrated measurement;
4. Impedance is within 5Ω of calibrated measurement.

11. MEASUREMENT UNCERTAINTY

SATIMO Uncertainty- SN 24/20 EP336 Measurement uncertainty for DUT averaged over 1 gram / 10 gram.									
Uncertainty Component	Sec.	Tol (+- %)	Prob. Dist.	Div.	Ci (1g)	Ci (10g)	1g Ui (+-%)	10g Ui (+-%)	vi
Measurement System									
Probe calibration	E.2.1	7.000	N	1	1	1	7.000	7.000	∞
Axial Isotropy	E.2.2	0.105	R	$\sqrt{3}$	√0.5	√0.5	0.043	0.043	∞
Hemispherical Isotropy	E.2.2	0.105	R	$\sqrt{3}$	√0.5	√0.5	0.043	0.043	∞
Boundary effect	E.2.3	1.000	R	$\sqrt{3}$	1	1	0.577	0.577	∞
Linearity	E.2.4	0.870	R	$\sqrt{3}$	1	1	0.502	0.502	∞
System detection limits	E.2.4	1.000	R	$\sqrt{3}$	1	1	0.577	0.577	∞
Modulation response	E2.5	3.000	R	$\sqrt{3}$	1	1	1.732	1.732	∞
Readout Electronics	E.2.6	0.021	N	1	1	1	0.021	0.021	∞
Response Time	E.2.7	0.000	R	$\sqrt{3}$	1	1	0.000	0.000	∞
Integration Time	E.2.8	1.400	R	$\sqrt{3}$	1	1	0.808	0.808	∞
RF ambient conditions-Noise	E.6.1	3.000	R	$\sqrt{3}$	1	1	1.732	1.732	∞
RF ambient conditions-reflections	E.6.1	3.000	R	$\sqrt{3}$	1	1	1.732	1.732	∞
Probe positioner mechanical tolerance	E.6.2	1.400	R	$\sqrt{3}$	1	1	0.808	0.808	∞
Probe positioning with respect to phantom shell	E.6.3	1.400	R	$\sqrt{3}$	1	1	0.808	0.808	∞
Extrapolation, interpolation, and integrations algorithms for max. SAR evaluation	E.5	2.300	R	$\sqrt{3}$	1	1	1.328	1.328	∞
Test sample Related									
Test sample positioning	E.4.2	2.6	N	1	1	1	2.600	2.600	∞
Device holder uncertainty	E.4.1	3	N	1	1	1	3.000	3.000	∞
Output power variation—SAR drift measurement	E.2.9	5	R	$\sqrt{3}$	1	1	2.887	2.887	∞
SAR scaling	E.6.5	5	R	$\sqrt{3}$	1	1	2.887	2.887	∞
Phantom and tissue parameters									
Phantom shell uncertainty—shape, thickness, and permittivity	E.3.1	4	R	$\sqrt{3}$	1	1	2.309	2.309	∞
Uncertainty in SAR correction for deviations in permittivity and conductivity	E.3.2	1.9	N	1	1	0.84	1.900	1.596	∞
Liquid conductivity measurement	E.3.3	2.5	R	$\sqrt{3}$	0.78	0.71	1.126	1.025	∞
Liquid permittivity measurement	E.3.3	4	N	1	0.78	0.71	3.120	2.840	M
Liquid conductivity—temperature uncertainty	E.3.4	2.5	R	$\sqrt{3}$	0.23	0.26	0.332	0.375	∞
Liquid permittivity—temperature uncertainty	E.3.4	5	N	1	0.23	0.26	1.150	1.300	M
Combined Standard Uncertainty			RSS				10.525	10.341	
Expanded Uncertainty (95% Confidence interval)			K=2				21.051	20.681	

SATIMO Uncertainty- SN 24/20 EP336 System Validation uncertainty for DUT averaged over 1 gram / 10 gram.									
Uncertainty Component	Sec.	Tol (+- %)	Prob. Dist.	Div.	Ci (1g)	Ci (10g)	1g Ui (+-%)	10g Ui (+-%)	vi
Measurement System									
Probe calibration	E.2.1	7	N	1	1	1	7.000	7.000	∞
Axial Isotropy	E.2.2	0.105	R	$\sqrt{3}$	1	1	0.061	0.061	∞
Hemispherical Isotropy	E.2.2	0.105	R	$\sqrt{3}$	0	0	0.000	0.000	∞
Boundary effect	E.2.3	1	R	$\sqrt{3}$	1	1	0.577	0.577	∞
Linearity	E.2.4	0.870	R	$\sqrt{3}$	1	1	0.502	0.502	∞
System detection limits	E.2.4	1.0	R	$\sqrt{3}$	1	1	0.58	0.58	∞
Modulation response	E2.5	3.0	R	$\sqrt{3}$	0	0	0.00	0.00	∞
Readout Electronics	E.2.6	0.021	N	1	1	1	0.021	0.021	∞
Response Time	E.2.7	0.0	R	$\sqrt{3}$	0	0	0.00	0.00	∞
Integration Time	E.2.8	1.4	R	$\sqrt{3}$	0	0	0.00	0.00	∞
RF ambient conditions-Noise	E.6.1	3.0	R	$\sqrt{3}$	1	1	1.73	1.73	∞
RF ambient conditions-reflections	E.6.1	3.0	R	$\sqrt{3}$	1	1	1.73	1.73	∞
Probe positioner mechanical tolerance	E.6.2	1.4	R	$\sqrt{3}$	1	1	0.81	0.81	∞
Probe positioning with respect to phantom shell	E.6.3	1.4	R	$\sqrt{3}$	1	1	0.81	0.81	∞
Extrapolation, interpolation, and integrations algorithms for max. SAR evaluation	E.5	2.3	R	$\sqrt{3}$	1	1	1.33	1.33	∞
System validation source									
Deviation of experimental dipole from numerical dipole	E.6.4	5.0	N	1	1	1	5.00	5.00	∞
Input power and SAR drift measurement	8,6.6.4	5.0	R	$\sqrt{3}$	1	1	2.89	2.89	∞
Dipole axis to liquid distance	8,E.6.6	2.0	R	$\sqrt{3}$	1	1	1.15	1.15	∞
Phantom and set-up									
Phantom shell uncertainty—shape, thickness, and permittivity	E.3.1	4.0	R	$\sqrt{3}$	1	1	2.31	2.31	∞
Uncertainty in SAR correction for deviations in permittivity and conductivity	E.3.2	1.9	N	1	1	0.84	1.90	1.60	∞
Liquid conductivity（temperature uncertainty）	E.3.3	2.5	R	$\sqrt{3}$	0.78	0.71	1.13	1.02	∞
Liquid conductivity（measured）	E.3.3	4	N	1	0.78	0.71	3.12	2.84	M
Liquid permittivity（temperature uncertainty）	E.3.4	2.5	R	$\sqrt{3}$	0.23	0.26	0.33	0.38	∞
Liquid permittivity（measured）	E.3.4	5	N	1	0.23	0.26	1.15	1.30	M
Combined Standard Uncertainty			RSS				10.458	10.272	
Expanded Uncertainty (95% Confidence interval)			K=2				20.916	20.544	

SATIMO Uncertainty- SN 24/20 EP336 System Check uncertainty for DUT averaged over 1 gram / 10 gram.									
Uncertainty Component	Sec.	Tol (+- %)	Prob. Dist.	Div.	Ci (1g)	Ci (10g)	1g Ui (+-%)	10g Ui (+-%)	vi
Measurement System									
Probe calibration drift	E.2.1.3	0.5	N	1	1	1	0.50	0.50	∞
Axial Isotropy	E.2.2	0.105	R	$\sqrt{3}$	0	0	0.00	0.00	∞
Hemispherical Isotropy	E.2.2	0.105	R	$\sqrt{3}$	0	0	0.00	0.00	∞
Boundary effect	E.2.3	1	R	$\sqrt{3}$	0	0	0.00	0.00	∞
Linearity	E.2.4	0.870	R	$\sqrt{3}$	0	0	0.00	0.00	∞
System detection limits	E.2.4	1.0	R	$\sqrt{3}$	0	0	0.00	0.00	∞
Modulation response	E2.5	3.0	R	$\sqrt{3}$	0	0	0.00	0.00	∞
Readout Electronics	E.2.6	0.021	N	1	0	0	0.00	0.00	∞
Response Time	E.2.7	0	R	$\sqrt{3}$	0	0	0.00	0.00	∞
Integration Time	E.2.8	1.4	R	$\sqrt{3}$	0	0	0.00	0.00	∞
RF ambient conditions-Noise	E.6.1	3.0	R	$\sqrt{3}$	0	0	0.00	0.00	∞
RF ambient conditions-reflections	E.6.1	3.0	R	$\sqrt{3}$	0	0	0.00	0.00	∞
Probe positioner mechanical tolerance	E.6.2	1.4	R	$\sqrt{3}$	1	1	0.81	0.81	∞
Probe positioning with respect to phantom shell	E.6.3	1.4	R	$\sqrt{3}$	1	1	0.81	0.81	∞
Extrapolation, interpolation, and integrations algorithms for max. SAR evaluation	E.5	2.3	R	$\sqrt{3}$	0	0	0.00	0.00	∞
System check source (dipole)									
Deviation of experimental dipoles	E.6.4	2.0	N	1	1	1	2.00	2.00	∞
Input power and SAR drift measurement	8,6.6.4	5.0	R	$\sqrt{3}$	1	1	2.89	2.89	∞
Dipole axis to liquid distance	8,E.6.6	2.0	R	$\sqrt{3}$	1	1	1.15	1.15	∞
Phantom and tissue parameters									
Phantom shell uncertainty—shape, thickness, and permittivity	E.3.1	4	R	$\sqrt{3}$	1	1	2.31	2.31	∞
Uncertainty in SAR correction for deviations in permittivity and conductivity	E.3.2	1.9	N	1	1	0.84	1.90	1.60	∞
Liquid conductivity measurement	E.3.3	2.5	R	$\sqrt{3}$	0.78	0.71	1.13	1.02	∞
Liquid permittivity measurement	E.3.3	4	N	1	0.78	0.71	3.12	2.84	M
Liquid conductivity—temperature uncertainty	E.3.4	2.5	R	$\sqrt{3}$	0.23	0.26	0.33	0.38	∞
Liquid permittivity—temperature uncertainty	E.3.4	5	N	1	0.23	0.26	1.15	1.30	M
Combined Standard Uncertainty			RSS				5.562	5.203	
Expanded Uncertainty (95% Confidence interval)			K=2				11.124	10.406	

12. CONDUCTED POWER MEASUREMENT

GSM BAND

Mode	Frequency(MHz)	Avg. Burst Power(dBm)	Duty cycle Factor(dBm)	Frame Power(dBm)
Maximum Power <1>				
GSM 850	824.2	32.33	-9	23.33
	836.6	**32.84**	-9	23.84
	848.8	32.53	-9	23.53
GPRS 850 （1 Slot）	824.2	32.25	-9	23.25
	836.6	32.69	-9	23.69
	848.8	32.46	-9	23.46
GPRS 850 （2 Slot）	824.2	30.12	-6	24.12
	836.6	30.23	-6	24.23
	848.8	30.44	-6	**24.44**
GPRS 850 （3 Slot）	824.2	28.25	-4.26	23.99
	836.6	28.42	-4.26	24.16
	848.8	28.37	-4.26	24.11
GPRS 850 （4 Slot）	824.2	27.38	-3	24.38
	836.6	27.21	-3	24.21
	848.8	27.19	-3	24.19
EGPRS 850 （1 Slot）	824.2	26.85	-9	17.85
	836.6	26.20	-9	17.20
	848.8	25.91	-9	16.91
EGPRS 850 （2 Slot）	824.2	24.35	-6	18.35
	836.6	24.28	-6	18.28
	848.8	24.19	-6	18.19
EGPRS 850 （3 Slot）	824.2	22.02	-4.26	17.76
	836.6	22.10	-4.26	17.84
	848.8	22.13	-4.26	17.87
EGPRS 850 （4 Slot）	824.2	20.25	-3	17.25
	836.6	20.18	-3	17.18
	848.8	20.11	-3	17.11

Mode	Frequency(MHz)	Avg. Burst Power(dBm)	Duty cycle Factor(dBm)	Frame Power(dBm)
Maximum Power <2>				
GSM 850	824.2	31.63	-9	22.63
	836.6	31.79	-9	22.79
	848.8	31.43	-9	22.43
GPRS 850 (1 Slot)	824.2	31.22	-9	22.22
	836.6	31.50	-9	22.50
	848.8	31.41	-9	22.41
GPRS 850 (2 Slot)	824.2	30.06	-6	24.06
	836.6	30.18	-6	24.18
	848.8	30.37	-6	24.37
GPRS 850 (3 Slot)	824.2	28.20	-4.26	23.94
	836.6	28.35	-4.26	24.09
	848.8	28.28	-4.26	24.02
GPRS 850 (4 Slot)	824.2	27.30	-3	24.30
	836.6	27.15	-3	24.15
	848.8	27.10	-3	24.10

GSM BAND CONTINUE

Mode	Frequency(MHz)	Avg. Burst Power(dBm)	Duty cycle Factor(dBm)	Frame Power(dBm)
Maximum Power <1>				
PCS1900	1850.2	**30.57**	-9	21.57
	1880	30.52	-9	21.52
	1909.8	30.36	-9	21.36
GPRS1900（1 Slot）	1850.2	30.55	-9	21.55
	1880	30.46	-9	21.46
	1909.8	30.33	-9	21.33
GPRS1900（2 Slot）	1850.2	28.42	-6	22.42
	1880	28.63	-6	**22.63**
	1909.8	28.47	-6	22.47
GPRS1900（3 Slot）	1850.2	26.43	-4.26	22.17
	1880	26.58	-4.26	22.32
	1909.8	26.21	-4.26	21.95
GPRS1900（4 Slot）	1850.2	24.33	-3	21.33
	1880	24.25	-3	21.25
	1909.8	24.19	-3	21.19
EGPRS1900（1 Slot）	1850.2	25.89	-9	16.89
	1880	26.04	-9	17.04
	1909.8	26.20	-9	17.20
EGPRS1900（2 Slot）	1850.2	24.85	-6	18.85
	1880	24.71	-6	18.71
	1909.8	24.90	-6	18.90
EGPRS1900（3 Slot）	1850.2	22.42	-4.26	18.16
	1880	22.35	-4.26	18.09
	1909.8	22.47	-4.26	18.21
EGPRS1900（4 Slot）	1850.2	21.25	-3	18.25
	1880	21.38	-3	18.38
	1909.8	21.43	-3	18.43

Mode	Frequency(MHz)	Avg. Burst Power(dBm)	Duty cycle Factor(dBm)	Frame Power(dBm)
Maximum Power <2>				
PCS1900	1850.2	29.61	-9	20.61
	1880	29.58	-9	20.58
	1909.8	29.30	-9	20.30
GPRS1900 （1 Slot）	1850.2	29.50	-9	20.50
	1880	29.42	-9	20.42
	1909.8	29.30	-9	20.30
GPRS1900 （2 Slot）	1850.2	28.33	-6	22.33
	1880	28.53	-6	22.53
	1909.8	28.20	-6	22.20
GPRS1900 （3 Slot）	1850.2	26.30	-4.26	22.04
	1880	26.41	-4.26	22.15
	1909.8	26.18	-4.26	21.92
GPRS1900 （4 Slot）	1850.2	24.26	-3	21.26
	1880	24.20	-3	21.20
	1909.8	24.13	-3	21.13

Note 1:
The Frame Power (Source-based time-averaged Power) is scaled the maximum burst average power based on time slots. The calculated methods are show as following:
Frame Power = Max burst power (1 Up Slot) – 9 dB
Frame Power = Max burst power (2 Up Slot) – 6 dB
Frame Power = Max burst power (3 Up Slot) – 4.26 dB
Frame Power = Max burst power (4 Up Slot) – 3 dB
Note 2:
SAR is not required for GPRS (1 Slot) Mode because its output power is less than of Voice Mode

UMTS BAND
HSDPA Setup Configuration:

·The EUT was connected to Base Station Agilent E5515C referred to the Setup Configuration.

·The RF path losses were compensated into the measurements.

·A call was established between EUT and Based Station with following setting:

(1) Set Gain Factors(βc and βd) parameters set according to each

(2) Set RMC 12.2Kbps+HSDPA mode.

(3) Set Cell Power=-86dBm

(4) Set HS-DSCH Configuration Type to FRC (H-set 1, QPSK)

(5) Select HSDPA Uplink Parameters

(6) Set Delta ACK, Delta NACK and Delta CQI=8

(7) Set Ack - Nack Repetition Factor to 3

(8) Set CQI Feedback Cycle (k) to 4ms

(9) Set CQI Repetition Factor to 2

(10) Power Ctrl Mode=All Up bits

·The transmitted maximum output power was recorded.

Table C.10.2.4: β values for transmitter characteristics tests with HS-DPCCH

Sub-test	βc (Note5)	βd	βd (SF)	βc/βd	βHS (Note1, Note 2)	CM (dB) (Note 3)	MPR (dB) (Note 3)
1	2/15	15/15	64	2/15	4/15	0.0	0.0
2	12/15(Note 4)	15/15(Note 4)	64	12/15(Note 4)	24/15	1.0	0.0
3	15/15	8/15	64	15/8	30/15	1.5	0.5
4	15/15	4/15	64	15/4	30/15	1.5	0.5

Note 1: ΔACK, ΔNACK and ΔCQI = 30/15 with β_{hs} = 30/15 * β_c .
Note 2: For the HS-DPCCH power mask requirement test in clause 5.2C, 5.7A, and the Error Vector Magnitude (EVM) with HS-DPCCH test in clause 5.13.1A, and HSDPA EVM with phase discontinuity in clause 5.13.1AA, ΔACK and ΔNACK = 30/15 with β_{hs} = 30/15 * β_c , and ΔCQI = 24/15 with β_{hs} = 24/15 * β_c .
Note 3: CM = 1 for βc/βd =12/15, hs/ c=24/15. For all other combinations of DPDCH, DPCCH and HS-DPCCH the MPR is based on the relative CM difference. This is applicable for only UEs that support HSDPA in release 6 and later releases.
Note 4: For subtest 2 the c/ d ratio of 12/15 for the TFC during the measurement period (TF1, TF0) is achieved by setting the signalled gain factors for the reference TFC (TF1, TF1) to c = 11/15 and d = 15/15.

HSUPA Setup Configuration:

· The EUT was connected to Base Station Agilent E5515C referred to the Setup Configuration.

· The RF path losses were compensated into the measurements.

· A call was established between EUT and Base Station with following setting * :

(1) Call Configs = 5.2B, 5.9B, 5.10B, and 5.13.2B with QPSK

(2) Set the Gain Factors (βc and βd) and parameters (AG Index) were set according to each specific sub-test in the following table, C11.1.3, quoted from the TS 34.121

(3) Set Cell Power = -86 dBm

(4) Set Channel Type = 12.2k + HSPA

(5) Set UE Target Power

(6) Power Ctrl Mode= Alternating bits

(7) Set and observe the E-TFCI

(8) Confirm that E-TFCI is equal to the target E-TFCI of 75 for sub-test 1, and other subtest's E-TFCI

· The transmitted maximum output power was recorded.

Table C.11.1.3: β values for transmitter characteristics tests with HS-DPCCH and E-DCH

Sub-test	βc	βd	βd (SF)	βc/βd	βHS (Note 1)	βec	βed (Note 4) (Note 5)	βed (SF)	βed (Codes)	CM (dB) (Note 2)	MPR (dB) (Note 2) (Note 6)	AG Index (Note 5)	E-TFCI
1	11/15 (Note 3)	15/15 (Note 3)	64	11/15 (Note 3)	22/15	209/225	1309/225	4	1	1.0	0.0	20	75
2	6/15	15/15	64	6/15	12/15	12/15	94/75	4	1	3.0	2.0	12	67
3	15/15	9/15	64	15/9	30/15	30/15	βed1: 47/15 βed2: 47/15	4 4	2	2.0	1.0	15	92
4	2/15	15/15	64	2/15	4/15	2/15	56/75	4	1	3.0	2.0	17	71
5	15/15	0	-	-	5/15	5/15	47/15	4	1	1.0	0.0	12	67

Note 1: For sub-test 1 to 4, ΔACK, ΔNACK and ΔCQI = 30/15 with β_{hs} = 30/15 * β_c. For sub-test 5, ΔACK, ΔNACK and ΔCQI = 5/15 with β_{hs} = 5/15 * β_c.
Note 2: CM = 1 for βc/βd =12/15, hs/ c=24/15. For all other combinations of DPDCH, DPCCH, HS-DPCCH, E-DPDCH and E-DPCCH the MPR is based on the relative CM difference.
Note 3: For subtest 1 the c/ d ratio of 11/15 for the TFC during the measurement period (TF1, TF0) is achieved by setting the signalled gain factors for the reference TFC (TF1, TF1) to c = 10/15 and d = 15/15.
Note 4: In case of testing by UE using E-DPDCH Physical Layer category 1, Sub-test 3 is omitted according to TS25.306 Table 5.1g.
Note 5: βed cannot be set directly; it is set by Absolute Grant Value.
Note 6: For subtests 2, 3 and 4, UE may perform E-DPDCH power scaling at max power which could results in slightly smaller MPR values.

UMTS BAND II

Mode	Frequency (MHz)	Avg. Burst Power (dBm)
WCDMA 1900 RMC	1852.4	23.83
	1880	23.97
	1907.6	**24.04**
WCDMA 1900 AMR	1852.4	23.37
	1880	23.33
	1907.6	23.51
HSDPA Subtest 1	1852.4	22.55
	1880	22.66
	1907.6	22.74
HSDPA Subtest 2	1852.4	21.85
	1880	21.92
	1907.6	21.99
HSDPA Subtest 3	1852.4	21.91
	1880	22.00
	1907.6	21.91
HSDPA Subtest 4	1852.4	21.87
	1880	21.97
	1907.6	21.86
HSUPA Subtest 1	1852.4	20.41
	1880	20.48
	1907.6	20.39
HSUPA Subtest 2	1852.4	20.43
	1880	20.59
	1907.6	20.61
HSUPA Subtest 3	1852.4	21.45
	1880	21.46
	1907.6	21.50
HSUPA Subtest 4	1852.4	19.80
	1880	19.89
	1907.6	20.09
HSUPA Subtest 5	1852.4	19.41
	1880	19.55
	1907.6	19.64

UMTS BAND IV

Mode	Frequency (MHz)	Avg. Burst Power (dBm)
WCDMA 1700 RMC	1712.5	22.96
	1732.5	23.10
	1752.5	**23.20**
WCDMA 1700 AMR	1712.5	22.85
	1732.5	22.79
	1752.5	22.91
HSDPA Subtest 1	1712.5	22.36
	1732.5	22.51
	1752.5	22.55
HSDPA Subtest 2	1712.5	21.66
	1732.5	21.77
	1752.5	21.90
HSDPA Subtest 3	1712.5	21.74
	1732.5	21.84
	1752.5	21.82
HSDPA Subtest 4	1712.5	21.77
	1732.5	21.84
	1752.5	21.97
HSUPA Subtest 1	1712.5	20.20
	1732.5	20.28
	1752.5	20.32
HSUPA Subtest 2	1712.5	20.25
	1732.5	20.32
	1752.5	20.35
HSUPA Subtest 3	1712.5	21.16
	1732.5	21.30
	1752.5	21.35
HSUPA Subtest 4	1712.5	19.56
	1732.5	19.84
	1752.5	19.88
HSUPA Subtest 5	1712.5	19.12
	1732.5	19.22
	1752.5	19.23

UMTS BAND V

Mode	Frequency (MHz)	Avg. Burst Power (dBm)
WCDMA 850 RMC	826.4	23.69
	836.6	23.66
	846.6	**23.75**
WCDMA 850 AMR	826.4	23.58
	836.6	23.47
	846.6	23.61
HSDPA Subtest 1	826.4	22.30
	836.6	22.36
	846.6	22.42
HSDPA Subtest 2	826.4	21.56
	836.6	21.48
	846.6	21.60
HSDPA Subtest 3	826.4	21.48
	836.6	21.39
	846.6	21.55
HSDPA Subtest 4	826.4	21.49
	836.6	21.33
	846.6	21.58
HSUPA Subtest 1	826.4	20.16
	836.6	20.11
	846.6	20.20
HSUPA Subtest 2	826.4	20.14
	836.6	20.17
	846.6	20.24
HSUPA Subtest 3	826.4	21.14
	836.6	21.09
	846.6	21.15
HSUPA Subtest 4	826.4	19.72
	836.6	19.67
	846.6	19.61
HSUPA Subtest 5	826.4	19.25
	836.6	18.95
	846.6	19.27

According to 3GPP 25.101 sub-clause 6.2.2 , the maximum output power is allowed to be reduced by following the table.

Table 6.1aA: UE maximum output power with HS-DPCCH and E-DCH

UE Transmit Channel Configuration	CM(db)	MPR(db)
For all combinations of ,DPDCH,DPCCH HS-DPDCH,E-DPDCH and E-DPCCH	0≤ CM≤3.5	MAX(CM-1,0)
Note: CM=1 for β_c/β_d=12/15, β_{hs}/β_c=24/15.For all other combinations of DPDCH, DPCCH, HS-DPCCH, E-DPDCH and E-DPCCH the MPR is based on the relative CM difference.		

The device supports MPR to solve linearity issues (ACLR or SEM) due to the higher peak-to average ratios (PAR) of the HSUPA signal. This prevents saturating the full range of the TX DAC inside of device and provides a reduced power output to the RF transceiver chip according to the Cubic Metric (a function of the combinations of DPDCH, DPCCH, HS-DPCCH, E-DPDCH and E-DPCCH).

When E-DPDCH channels are present the beta gains on those channels are reduced firsts to try to get the power under the allowed limit. If the beta gains are lowered as far as possible, then a hard limiting is applied at the maximum allowed level.

The SW currently recalculates the cubic metric every time the beta gains on the E-DPDCH are reduced. The cubic metric will likely get lower each time this is done .However, there is no reported reduction of maximum output power in the HSUPA mode since the device also provides a compensation for the power back-off by increasing the gain of TX_AGC in the transceiver (PA) device.

The end effect is that the DUT output power is identical to the case where there is no MPR in the device.

LTE Band

Conducted Power of LTE Band 2(dBm)							
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 18607	Channel 18900	Channel 19193
1.4MHz	QPSK	1	0	0	24.46	24.57	24.67
			3	0	24.58	24.63	24.80
			5	0	24.47	24.56	24.72
		3	0	0	24.55	24.62	24.69
			2	0	24.55	24.63	24.69
			3	0	24.55	24.66	24.72
		6	0	1	23.55	23.64	23.75
	16QAM	1	0	1	23.56	23.68	23.56
			3	1	23.72	23.85	23.72
			5	1	23.61	23.72	23.54
		3	0	1	23.56	23.63	23.70
			2	1	23.53	23.62	23.69
			3	1	23.54	23.70	23.75
		6	0	2	22.57	22.54	22.71
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 18615	Channel 18900	Channel 19185
3MHz	QPSK	1	0	0	24.49	24.66	24.77
			7	0	24.51	24.66	24.77
			14	0	24.50	24.63	24.75
		8	0	1	23.50	23.65	23.74
			4	1	23.50	23.62	23.75
			7	1	23.52	23.62	23.76
		15	0	1	23.50	23.60	23.76
	16QAM	1	0	1	23.71	23.83	23.64
			7	1	23.70	23.76	23.67
			14	1	23.68	23.76	23.67
		8	0	2	23.52	23.61	23.74
			4	2	23.48	23.62	23.73
			7	2	23.51	23.62	23.72
		15	0	2	22.52	22.56	22.63

Conducted Power of LTE Band 2(dBm)							
Bandwidth	**Modulation**	**RB size**	**RB offset**	**Target MPR**	**Channel 18625**	**Channel 18900**	**Channel 19175**
5MHz	QPSK	1	0	0	24.52	24.62	24.76
			13	0	24.62	24.73	**24.89**
			24	0	24.47	24.62	24.75
		12	0	1	23.54	23.66	23.72
			6	1	23.52	23.67	23.73
			13	1	23.51	23.62	23.75
		25	0	1	23.56	23.67	23.75
	16QAM	1	0	1	23.52	23.79	23.70
			13	1	23.61	23.95	23.85
			24	1	23.46	23.79	23.73
		12	0	2	23.58	23.64	23.76
			6	2	23.51	23.65	23.75
			13	2	23.50	23.64	23.73
		25	0	2	22.55	22.63	22.78
Bandwidth	**Modulation**	**RB size**	**RB offset**	**Target MPR**	**Channel 18650**	**Channel 18900**	**Channel 19150**
10MHz	QPSK	1	0	0	24.55	24.69	24.76
			25	0	24.60	24.70	24.85
			49	0	24.58	24.66	24.79
		25	0	1	23.60	23.71	23.79
			13	1	23.59	23.70	23.76
			25	1	23.62	23.71	23.82
		50	0	1	23.61	23.69	23.74
	16QAM	1	0	1	23.71	23.75	23.65
			25	1	23.81	23.91	23.79
			49	1	23.69	23.82	23.70
		25	0	2	23.60	23.71	23.77
			13	2	23.59	23.72	23.76
			25	2	23.62	23.75	23.79
		50	0	2	22.57	22.69	22.70

Conducted Power of LTE Band 2(dBm)							
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 18675	Channel 18900	Channel 19125
15MHz	QPSK	1	0	0	24.49	24.61	24.69
			38	0	24.54	24.65	24.73
			74	0	24.47	24.60	24.71
		36	0	1	23.69	23.71	23.80
			18	1	23.70	23.73	23.79
			39	1	23.67	23.72	23.80
		75	0	1	23.65	23.72	23.79
	16QAM	1	0	1	23.66	23.87	23.56
			38	1	23.68	23.92	23.64
			74	1	23.67	23.87	23.58
		36	0	2	23.70	23.70	23.80
			18	2	23.65	23.72	23.80
			39	2	23.65	23.73	23.80
		75	0	2	22.55	22.68	22.75
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 18700	Channel 18900	Channel 19100
20MHz	QPSK	1	0	0	24.57	24.60	24.53
			50	0	24.76	24.75	24.71
			99	0	24.60	24.62	24.57
		50	0	1	23.51	23.57	23.75
			25	1	23.52	23.58	23.72
			50	1	23.62	23.62	23.74
		100	0	1	23.53	23.59	23.72
	16QAM	1	0	1	23.54	23.74	23.59
			50	1	23.66	23.92	23.81
			99	1	23.58	23.72	23.65
		50	0	2	23.55	23.59	23.73
			25	2	23.52	23.57	23.73
			50	2	23.62	23.63	23.73
		100	0	2	22.52	22.57	22.71

Conducted Power of LTE Band 4(dBm)							
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 19957	Channel 20175	Channel 20393
1.4MHz	QPSK	1	0	0	23.81	23.82	23.89
			3	0	23.87	23.94	**24.03**
			5	0	23.81	23.85	23.89
		3	0	0	23.85	23.89	23.96
			2	0	23.86	23.93	23.94
			3	0	23.85	23.96	23.98
		6	0	1	22.83	22.92	22.94
	16QAM	1	0	1	22.89	23.01	22.77
			3	1	23.04	23.18	22.94
			5	1	22.91	22.95	22.74
		3	0	1	23.87	23.91	23.96
			2	1	23.85	23.91	23.96
			3	1	23.84	23.96	23.93
		6	0	2	21.86	21.79	21.90
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 19965	Channel 20175	Channel 20385
3MHz	QPSK	1	0	0	23.84	23.92	23.92
			7	0	23.85	23.92	23.91
			14	0	23.88	23.89	23.92
		8	0	1	22.85	22.85	22.92
			4	1	22.82	22.87	22.92
			7	1	22.87	22.86	22.92
		15	0	1	22.86	22.91	22.89
	16QAM	1	0	1	23.02	23.07	22.78
			7	1	23.00	23.03	22.83
			14	1	23.03	23.01	22.84
		8	0	2	22.83	22.86	22.89
			4	2	22.82	22.86	22.88
			7	2	22.80	22.90	22.89
		15	0	2	21.86	21.79	21.85

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Conducted Power of LTE Band 4(dBm)							
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 19975	Channel 20175	Channel 20375
5MHz	QPSK	1	0	0	23.78	23.89	23.89
			13	0	23.98	23.96	24.02
			24	0	23.83	23.87	23.93
		12	0	1	22.82	22.87	22.90
			6	1	22.82	22.88	22.92
			13	1	22.89	22.85	22.91
		25	0	1	22.87	22.88	22.94
	16QAM	1	0	1	22.78	23.05	22.87
			13	1	22.95	23.12	23.02
			24	1	22.84	23.03	22.92
		12	0	2	22.81	22.90	22.89
			6	2	22.85	22.87	22.90
			13	2	22.90	22.88	22.93
		25	0	2	21.89	21.89	21.99
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 20000	Channel 20175	Channel 20350
10MHz	QPSK	1	0	0	23.76	23.85	23.75
			25	0	23.95	23.95	23.84
			49	0	23.86	23.86	23.73
		25	0	1	22.87	22.93	22.89
			13	1	22.89	22.93	22.90
			25	1	22.94	22.97	22.88
		50	0	1	22.89	22.75	22.87
	16QAM	1	0	1	22.97	23.04	22.62
			25	1	23.14	23.19	22.84
			49	1	23.02	23.00	22.77
		25	0	2	22.86	22.90	22.91
			13	2	22.90	22.93	22.92
			25	2	22.94	22.90	22.89
		50	0	2	21.86	21.80	21.91

Conducted Power of LTE Band 4(dBm)							
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 20025	Channel 20175	Channel 20325
15MHz	QPSK	1	0	0	23.68	23.78	23.81
			38	0	23.85	23.86	23.91
			74	0	23.76	23.76	23.80
		36	0	1	22.88	22.92	22.95
			18	1	22.87	22.92	22.94
			39	1	22.89	22.92	22.96
		75	0	1	22.87	22.91	22.91
	16QAM	1	0	1	22.85	23.08	22.72
			38	1	23.00	23.11	22.79
			74	1	22.96	22.99	22.72
		36	0	2	22.88	22.92	22.97
			18	2	22.88	22.92	22.94
			39	2	22.88	22.92	22.97
		75	0	2	21.80	21.86	21.92
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 20050	Channel 20175	Channel 20300
20MHz	QPSK	1	0	0	23.78	23.77	23.63
			50	0	24.05	23.99	23.93
			99	0	23.83	23.80	23.66
		50	0	1	22.82	22.83	22.83
			25	1	22.82	22.84	22.81
			50	1	22.84	22.89	22.86
		100	0	1	22.83	22.85	22.79
	16QAM	1	0	1	22.78	22.93	22.74
			50	1	23.07	23.17	22.93
			99	1	22.81	22.94	22.81
		50	0	2	22.84	22.84	22.79
			25	2	22.85	22.83	22.81
			50	2	22.87	22.87	22.86
		100	0	2	21.79	21.84	21.85

Conducted Power of LTE Band 5(dBm)							
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 20407	Channel 20525	Channel 20643
1.4MHz	QPSK	1	0	0	23.29	23.35	23.48
			3	0	23.41	23.47	23.67
			5	0	23.31	23.34	23.52
		3	0	0	23.38	23.42	23.59
			2	0	23.38	23.43	23.58
			3	0	23.34	23.47	23.58
		6	0	1	22.31	22.42	22.56
	16QAM	1	0	1	22.38	22.51	22.39
			3	1	22.59	22.66	22.68
			5	1	22.42	22.57	22.42
		3	0	1	23.33	23.44	23.60
			2	1	23.37	23.46	23.59
			3	1	23.34	23.48	23.59
		6	0	2	21.37	21.33	21.57
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 20415	Channel 20525	Channel 20635
3MHz	QPSK	1	0	0	23.33	23.40	23.61
			7	0	23.33	23.48	23.61
			14	0	23.37	23.46	23.59
		8	0	1	22.31	22.49	22.59
			4	1	22.34	22.49	22.60
			7	1	22.37	22.46	22.55
		15	0	1	22.35	22.46	22.56
	16QAM	1	0	1	22.56	22.67	22.53
			7	1	22.52	22.62	22.54
			14	1	22.53	22.63	22.53
		8	0	2	22.33	22.48	22.59
			4	2	22.35	22.49	22.59
			7	2	22.32	22.48	22.58
		15	0	2	21.35	21.44	21.55

Conducted Power of LTE Band 5(dBm)							
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 20425	Channel 20525	Channel 20625
5MHz	QPSK	1	0	0	23.35	23.43	23.57
			13	0	23.44	23.60	**23.70**
			24	0	23.40	23.50	23.62
		12	0	1	22.36	22.54	22.71
			6	1	22.35	22.53	22.67
			13	1	22.41	22.50	22.57
		25	0	1	22.39	22.55	22.65
	16QAM	1	0	1	22.37	22.68	22.54
			13	1	22.49	22.80	22.73
			24	1	22.39	22.66	22.63
		12	0	2	22.37	22.54	22.70
			6	2	22.38	22.52	22.67
			13	2	22.43	22.54	22.58
		25	0	2	21.42	21.54	21.68
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 20450	Channel 20525	Channel 20600
10MHz	QPSK	1	0	0	23.06	23.45	23.56
			25	0	23.43	23.11	22.51
			49	0	22.25	23.43	22.86
		25	0	1	21.88	21.70	21.79
			13	1	21.90	21.89	22.52
			25	1	21.73	21.91	21.38
		50	0	1	21.28	22.14	21.60
	16QAM	1	0	1	21.05	22.32	22.54
			25	1	21.34	23.33	22.01
			49	1	21.26	24.11	21.58
		25	0	2	21.78	24.00	22.25
			13	2	21.01	23.97	21.99
			25	2	21.51	23.32	21.98
		50	0	2	21.00	23.02	21.23

Conducted Power of LTE Band 7 (dBm)							
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 20775	Channel 21100	Channel 21425
5MHz	QPSK	1	0	0	23.30	23.61	23.87
			12	0	23.38	23.71	**24.02**
			24	0	23.33	23.61	23.89
		12	0	1	22.31	22.64	22.86
			6	1	22.33	22.67	22.68
			13	1	22.33	22.65	22.86
		25	0	1	22.32	22.66	22.70
	16QAM	1	0	1	22.29	22.79	22.86
			12	1	22.37	22.87	22.94
			24	1	22.30	22.79	22.79
		12	0	2	22.34	22.67	22.75
			6	2	22.34	22.62	22.55
			13	2	22.29	22.68	22.72
		25	0	2	21.41	21.64	21.76
Bandwidth	Modulation	RB size	RB offset	Target MPR	Channel 20800	Channel 21100	Channel 21400
10MHz	QPSK	1	0	0	23.22	23.54	23.82
			24	0	23.23	23.77	23.65
			49	0	23.08	23.66	23.59
		25	0	1	22.35	22.64	22.47
			12	1	22.42	22.63	22.46
			25	1	22.40	22.79	22.61
		50	0	1	22.37	22.69	22.55
	16QAM	1	0	1	21.94	22.73	22.26
			24	1	22.17	22.94	22.46
			49	1	22.11	22.80	22.39
		25	0	2	22.39	22.65	22.46
			12	2	22.41	22.66	22.46
			25	2	22.38	22.81	22.60
		50	0	2	21.43	21.77	21.54